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## Structure Reports

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## N,N-Bis(trifluoromethylsulfonyl)aniline

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The title molecule, $\mathrm{C}_{8} \mathrm{H}_{5} \mathrm{~F}_{6} \mathrm{NO}_{4} \mathrm{~S}_{2}$, has crystallographic twofold symmetry. The crystal packing consists of three intermolecular $\mathrm{C}-\mathrm{H} \cdots \mathrm{O}$ contacts, resulting in a two-dimensional network. In the third direction, only a very weak C $\mathrm{H} \cdots \mathrm{F}$ interaction, with an $\mathrm{H} \cdots \mathrm{F}$ distance of $2.83 \AA$, is found.

## Comment

The crystal structure determination of the title compound, (I), was undertaken to study the influence of the F atoms on the crystal packing.

## Key indicators

Single-crystal X-ray study
$T=143 \mathrm{~K}$
Mean $\sigma(\mathrm{C}-\mathrm{C})=0.001 \AA$
$R$ factor $=0.026$
$w R$ factor $=0.069$
Data-to-parameter ratio $=25.8$
For details of how these key indicators were automatically derived from the article, see http://journals.iucr.org/e.
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Figure 1
The structure of (I), with $50 \%$ probability displacement ellipsoids.

## Crystal data

$\mathrm{C}_{8} \mathrm{H}_{5} \mathrm{~F}_{6} \mathrm{NO}_{4} \mathrm{~S}_{2}$
$M_{r}=357.25$
Orthorhombic, Fdd2
$a=24.871$ (4) $\AA$
$b=5.6208(6) \AA$
$c=18.2216(19) \AA$
$V=2547.3(6) \AA^{3}$
$Z=8$
$D_{x}=1.863 \mathrm{Mg} \mathrm{m}^{-3}$

## Data collection

Siemens SMART CCD $\omega$ scans
Absorption correction: numerical (SHELXTL; Sheldrick, 1996)
$T_{\text {min }}=0.823, T_{\text {max }}=0.946$
13534 measured reflections
2529 independent reflections
2334 reflections with $I>2 \sigma(I)$

## Refinement

Refinement on $F^{2}$
$R\left[F^{2}>2 \sigma\left(F^{2}\right)\right]=0.026$
$w R\left(F^{2}\right)=0.069$
$S=1.20$
2529 reflections
98 parameters
H -atom parameters constrained
$w=1 /\left[\sigma^{2}\left(F_{o}^{2}\right)+(0.04 P)^{2}\right]$
where $P=\left(F_{o}{ }^{2}+2 F_{c}{ }^{2}\right) / 3$

## Mo $K \alpha$ radiation

Cell parameters from 234 reflections
$\theta=3-36^{\circ}$
$\mu=0.51 \mathrm{~mm}^{-1}$
$T=143$ (2) K
Rod, colorless
$0.50 \times 0.18 \times 0.12 \mathrm{~mm}$
$R_{\text {int }}=0.029$
$\theta_{\max }=35.0^{\circ}$
$h=-33 \rightarrow 39$
$k=-8 \rightarrow 9$
$l=-28 \rightarrow 26$
205 standard reflections
frequency: 600 min
intensity decay: none

[^0]

Figure 2
The crystal packing of (I), viewed down $b$.

Table 1
Hydrogen-bonding geometry $\left(\AA^{\circ},^{\circ}\right)$.

| $D-\mathrm{H} \cdots A$ | $D-\mathrm{H}$ | $\mathrm{H} \cdots A$ | $D \cdots A$ | $D-\mathrm{H} \cdots A$ |
| :--- | :--- | :--- | :--- | :--- |
| $\mathrm{C} 2-\mathrm{H} 2 \cdots \mathrm{O}^{\mathrm{i}}$ | 0.95 | 2.53 | $3.458(2)$ | 167 |
| $\mathrm{C} 4-\mathrm{H} 4 \cdots 1^{\mathrm{ii}}$ | 0.95 | 2.51 | $3.267(2)$ | 137 |

Symmetry codes: (i) $x, 1+y, z$; (ii) $x, \frac{1}{2}+y, z-\frac{1}{2}$.

The H atoms were taken from a difference Fourier synthesis. They were refined with fixed individual displacement parameters $\left[U_{\text {iso }}(\mathrm{H})\right.$ $=1.2 U_{\text {eq }}(\mathrm{C})$ ], using a riding model with fixed distances $(\mathrm{H}-\mathrm{C}=$ $0.95 \AA$ ).

Data collection: SMART (Siemens, 1995); cell refinement: SMART; data reduction: SAINT (Siemens, 1995); program(s) used to solve structure: SHELXS97 (Sheldrick, 1997); program(s) used to refine structure: SHELXL97 (Sheldrick, 1997); molecular graphics: $X P$ in SHELXTL (Sheldrick, 1996); software used to prepare material for publication: SHELXL97.

## References

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[^0]:    $(\Delta / \sigma)_{\max }=0.001$
    $\Delta \rho_{\text {max }}=0.29 \mathrm{e}^{-3}$
    $\Delta \rho_{\min }=-0.24 \mathrm{e}^{-3}$
    Extinction correction: SHELXL97
    Extinction coefficient: 0.00060 (14)
    Absolute structure: Flack (1983);
    1139 Friedel pairs
    Flack parameter $=0.00(5)$

